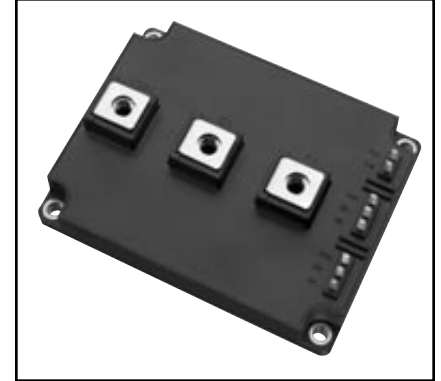
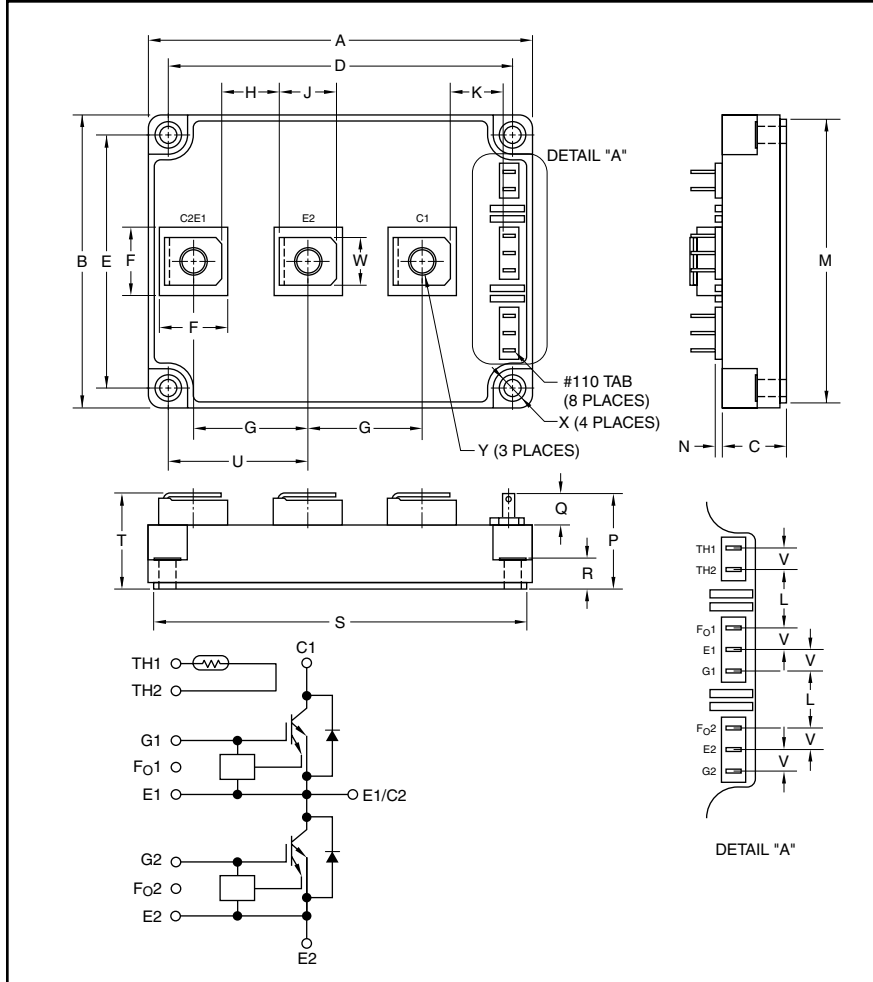


Dual IGBTMOD™ Compact IGBT Series Module 400 Amperes/1700 Volts



Description:

Powerex Dual IGBTMOD™ Compact IGBT Series Modules are designed for use in switching applications. Each module consists of two IGBT Transistors in a half-bridge configuration, with each transistor having a reverse-connected super-fast recovery free-wheel diode. All components and interconnects are isolated from the heat sinking baseplate, offering simplified system assembly and thermal management.

Features:

- Over-Current and Over-Temperature Protection
- Low $V_{CE(sat)}$
- Isolated Baseplate for Easy Heat Sinking

Applications:

- AC Motor Control
- Motion/Servo Control
- UPS
- Welding Power Supplies
- Laser Power Supplies

Ordering Information:

Example: Select the complete part number from the table below -i.e. MG400V2YS60A is a 1700V (V_{CES}), 400 Ampere Dual IGBTMOD™ Compact IGBT Series Module.

| Type | Current Rating Amperes | V_{CES} Volts (x 10) |
|------|---------------------------|---------------------------|
| MG | 400 | 170 |

Outline Drawing and Circuit Diagram

| Dimensions | Inches | Millimeters |
|------------|-----------|-------------|
| A | 4.92±0.04 | 125.0±1.0 |
| B | 3.78±0.04 | 96.0±1.0 |
| C | 0.84±0.04 | 21.3±1.0 |
| D | 4.49±0.03 | 113.0±0.8 |
| E | 3.30±0.03 | 84.0±0.8 |
| F | 0.86±0.04 | 22.0±1.0 |
| G | 1.46±0.04 | 37.0±1.0 |
| H | 0.75±0.04 | 19.0±1.0 |
| J | 0.71±0.04 | 18.0±1.0 |
| K | 0.73±0.04 | 18.6±1.0 |
| L | 0.59±0.04 | 15.0±1.0 |
| M | 3.66±0.03 | 93.0±0.8 |

| Dimensions | Inches | Millimeters |
|------------|-----------------|---------------|
| N | 0.07±0.04 | 1.8±1.0 |
| P | 1.24±0.04 | 31.5±1.0 |
| Q | 0.40±0.03 | 10.2±0.8 |
| R | 0.34±0.03 | 8.7±0.8 |
| S | 4.92±0.04 | 125.0±1.0 |
| T | 1.24-0.01/+0.04 | 31.5+2.0/-0.8 |
| U | 1.81±0.04 | 46.0±1.0 |
| V | 0.22±0.04 | 5.6±1.0 |
| W | 0.63±0.03 | 16.0±0.8 |
| X | 0.21 Dia. | 5.5 Dia. |
| Y | M8 Metric | M8 |

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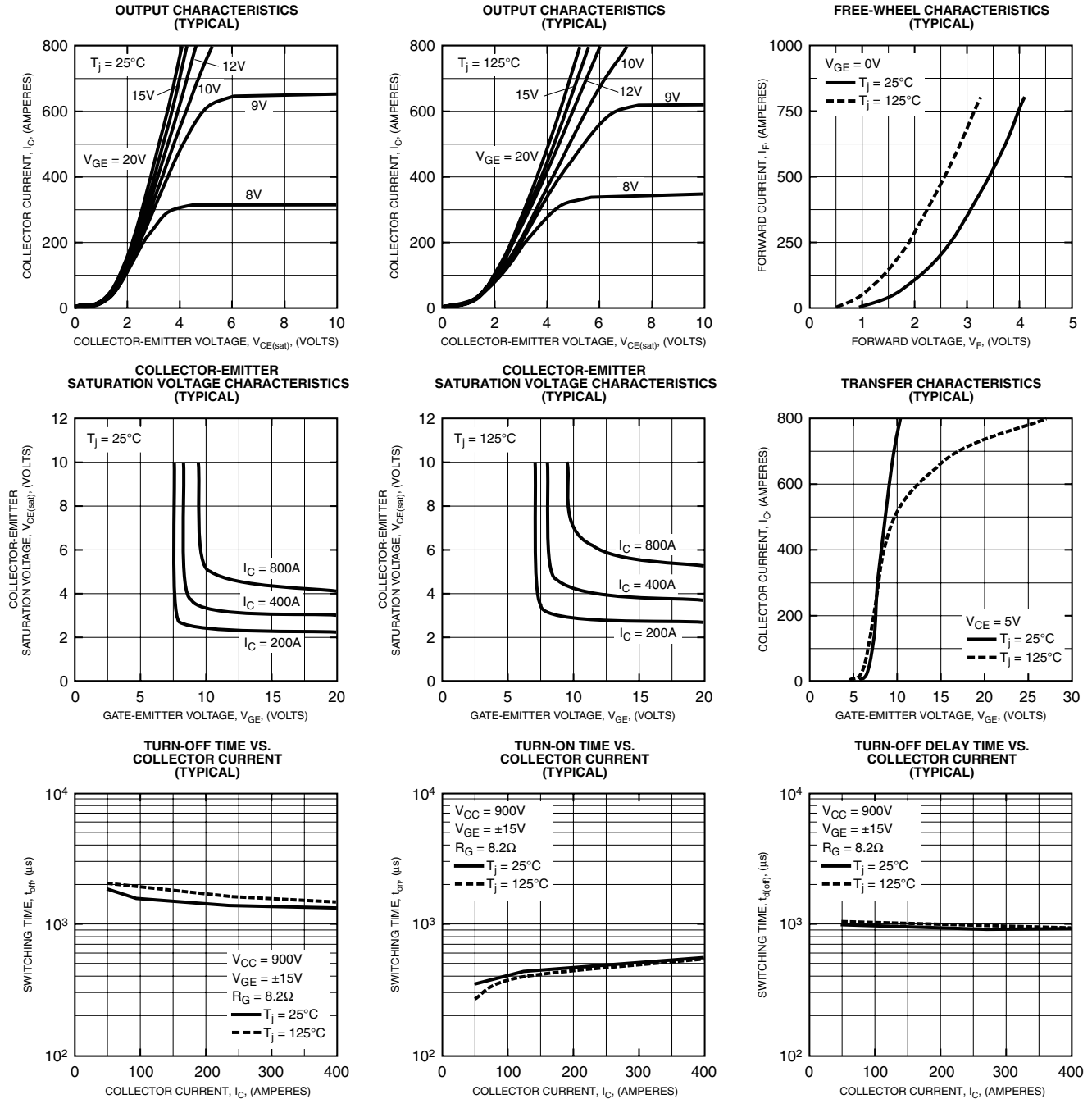
Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

| Characteristics | Symbol | MG400V2YS60A | Units |
|--|-----------|--------------|------------------|
| Collector-Emitter Voltage | V_{CES} | 1700 | Volts |
| Gate-Emitter Voltage | V_{GES} | ± 20 | Volts |
| Collector Current (DC) | I_C | 400 | Amperes |
| Forward Current (DC) | I_F | 400 | Amperes |
| Collector Dissipation ($T_C = 25^\circ\text{C}$) | P_C | 4300 | Watts |
| Power Device Junction Temperature | T_j | -20 to 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | -40 to 125 | $^\circ\text{C}$ |
| Mounting Torque, M5 Mounting Screws | — | 27 | in-lb |
| Mounting Torque, M8 Main Terminal Screws | — | 88 | in-lb |
| Module Weight (Typical) | — | 680 | Grams |
| Isolation Voltage, AC 1 minute, 60Hz Sinusoidal | V_{ISO} | 4000 | Volts |

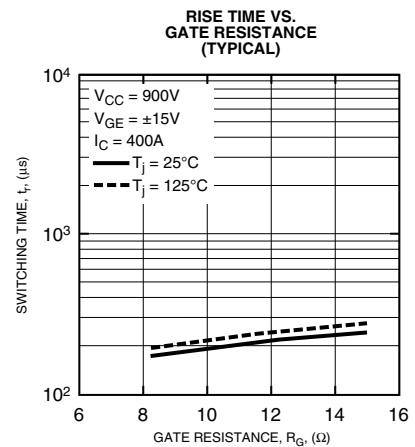
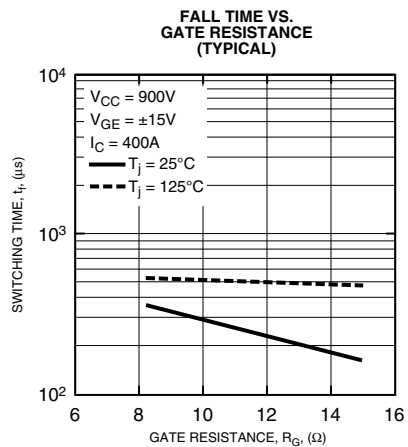
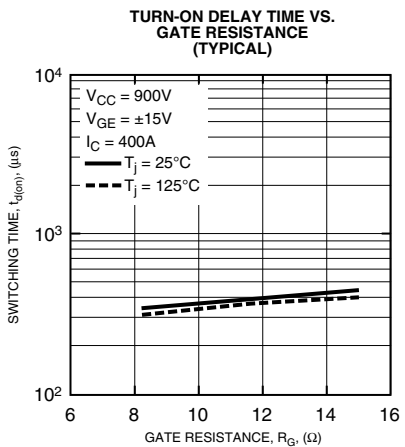
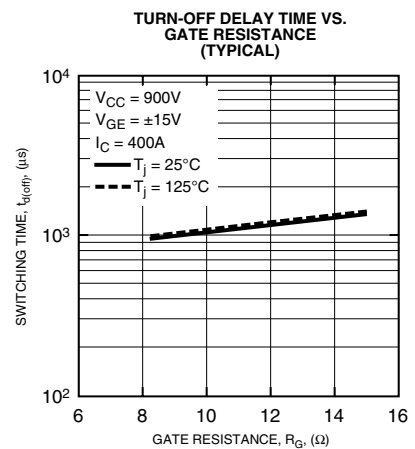
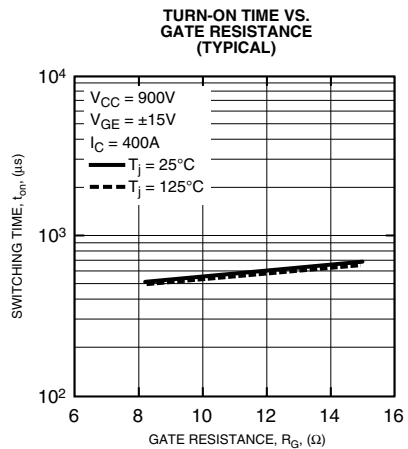
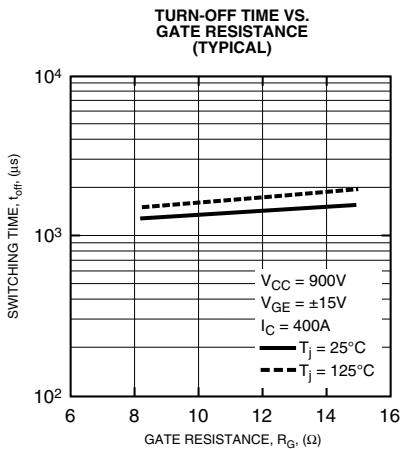
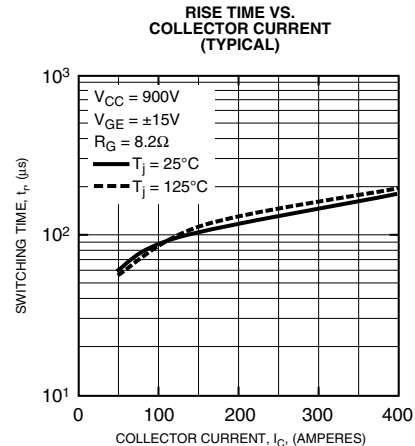
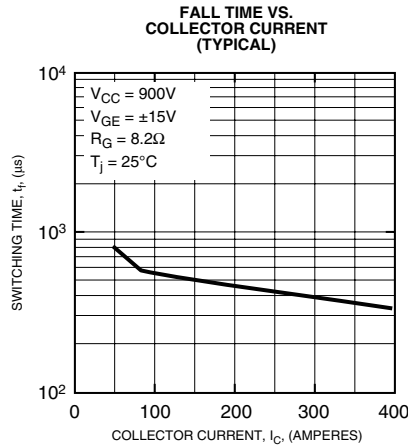
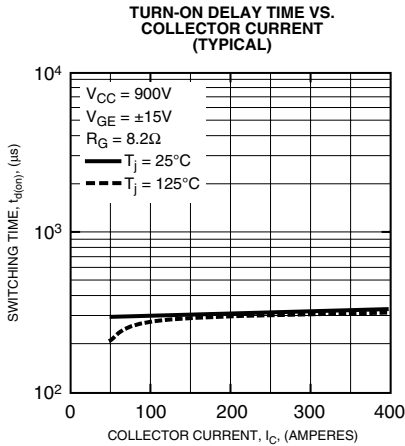
Electrical and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

| Characteristics | Symbol | Test Conditions | Min. | Typ. | Max. | Units |
|--------------------------------------|----------------|---|------|-------|----------|------------------------------|
| Gate Leakage Current | I_{GES} | $V_{GE} = \pm 20\text{V}, V_{CE} = 0\text{V}$ | — | — | ± 10 | μA |
| Collector Cutoff Current | I_{CES} | $V_{CE} = 1700\text{V}, V_{GE} = 0\text{V}$ | — | — | 1.0 | mA |
| Gate-Emitter Cutoff Voltage | $V_{GE(off)}$ | $I_C = 400\text{mA}, V_{CE} = 5\text{V}$ | 4.5 | 5.5 | 6.5 | Volts |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | $V_{GE} = 15\text{V}, I_C = 400\text{A}, T_j = 25^\circ\text{C}$ | — | 3.0 | 3.4 | Volts |
| | | $V_{GE} = 15\text{V}, I_C = 400\text{A}, T_j = 125^\circ\text{C}$ | — | 3.8 | 4.2 | Volts |
| Input Capacitance | C_{ies} | $V_{CE} = 10\text{V}, V_{GE} = 0\text{V}, f = 1\text{MHz}$ | — | 45000 | — | pF |
| Gate-Emitter Voltage | V_{GE} | | 13.0 | 15.0 | 17.0 | Volts |
| Gate Resistance | R_G | | 8.2 | — | 15.0 | Ω |
| Inductive Load | $t_{d(on)}$ | | — | 0.35 | — | μs |
| Switching | t_r | | — | 0.2 | — | μs |
| Times | t_{on} | $V_{CC} = 900\text{V}, I_C = 400\text{A},$ | — | 0.55 | — | μs |
| | $t_{d(off)}$ | $V_{GE} = \pm 15\text{V}, R_G = 8.2\Omega$ | — | 0.9 | — | μs |
| | t_f | | — | 0.4 | 0.6 | μs |
| | t_{off} | | — | 1.3 | — | μs |
| Forward Voltage | V_F | $I_F = 400\text{A}, V_{GE} = 0\text{V}, T_j = 25^\circ\text{C}$ | — | 3.2 | 4.2 | Volts |
| | | $I_F = 400\text{A}, V_{GE} = 0\text{V}, T_j = 125^\circ\text{C}$ | — | 2.4 | — | Volts |
| Reverse Recovery Time | t_{rr} | $I_F = 400\text{A}, V_{GE} = -15\text{V}, di/dt = 2000\text{A}/\mu\text{s}$ | — | 0.2 | 0.4 | μs |
| Junction to Case Thermal Resistance | $R_{th(j-c)Q}$ | IGBT (Per 1/2 Module) | — | — | 0.029 | $^\circ\text{C}/\text{Watt}$ |
| | $R_{th(j-c)D}$ | FWDi (Per 1/2 Module) | — | — | 0.056 | $^\circ\text{C}/\text{Watt}$ |
| RTC Operating Current | I_{rtc} | $T_j = 25^\circ\text{C}$ | 800 | — | — | Amperes |

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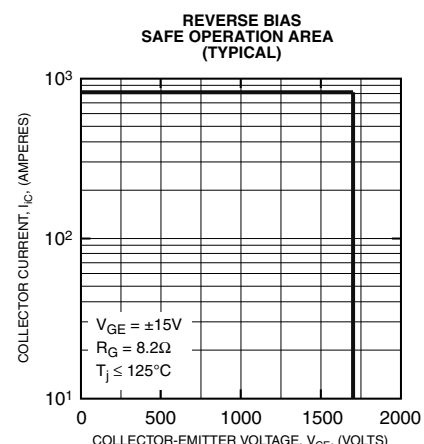
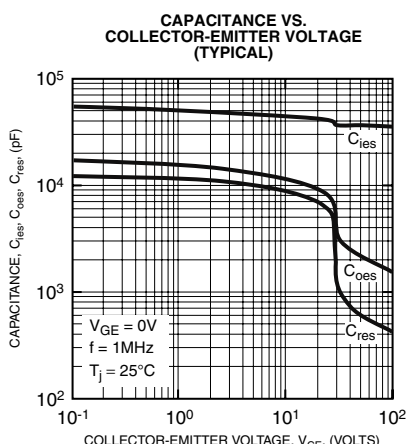
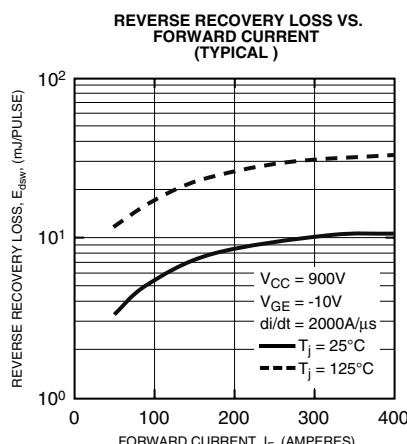
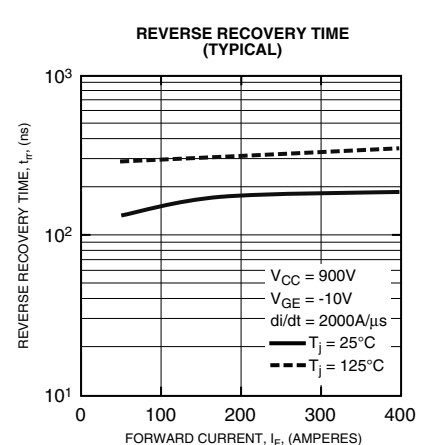
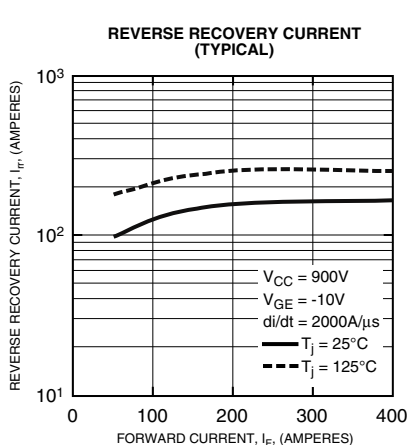
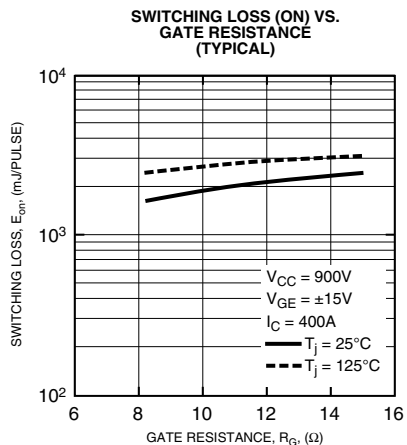
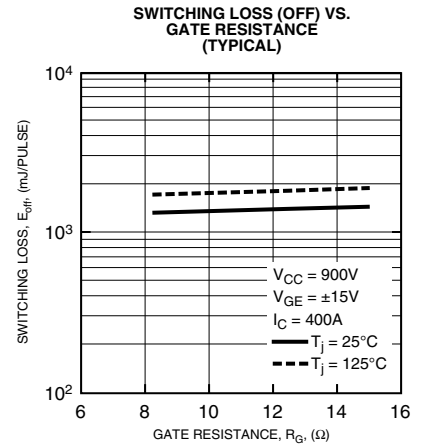
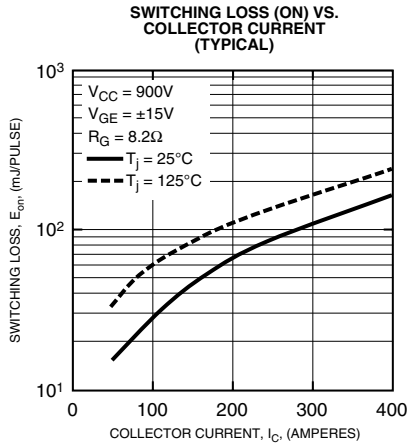
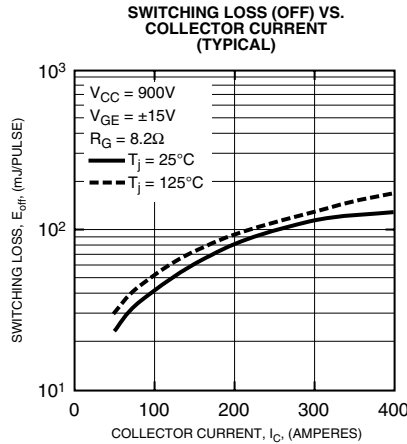
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Powerex, Inc., 200 E. Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

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